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TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VHCV574FT,TC74VHCV574FK

Octal Schmitt D-Type Flip Flop with 3-State Output

The TC74VHCV574 is advanced high speed CMOS OCTAL FLIP-FLOP with 3-STATE OUTPUT fabricated with silicon gate CMOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This 8-bit D-type flip-flop is controlled by a clock input (CK) and an output enable input (\overline{OE}).

When the $\ \overline{OE}\$ input is high, the eight outputs are in a high impedance state.

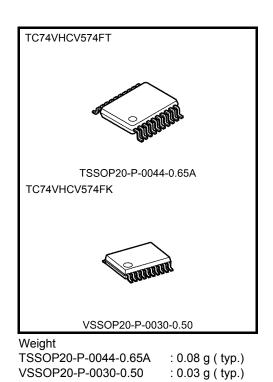
Input pin have hysteresis between the positive-going and negative-going thresholds. Thus the TC74VHCV574 is capable of squaring up transitions of slowly changing input signals and provides an improved noise immunity.

Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output $^{(Note)}$ pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, etc.

Note: Output in off-state.

Features

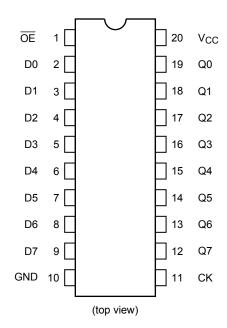
- High speed: $f_{max} = 180 \text{ MHz}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 2 \mu A \pmod{at Ta} = 25 \circ C$
- Wide operating voltage range: V_{CC} (opr) = 1.8 V to 5.5 V
- Ouput current: $|I_{OH}|/I_{OL} = 16 \text{ mA} (\text{min}) (V_{CC} = 4.5 \text{ V})$
- Available in TSSOP and VSSOP (US)
- Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 574 type



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Pin Assignment



Truth Table

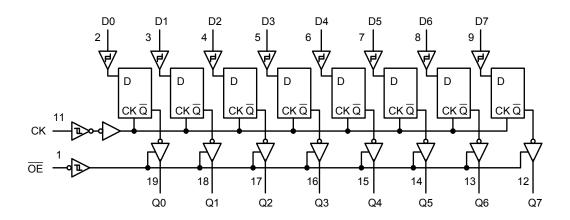
	Inputs	Output	
ŌĒ	СК	D	Output
Н	Х	Х	Z
L		Х	Qn
L		L	L
L		Н	Н

X: Don't care

Z: High impedance

Qn: No change

System Diagram



Absolute Maximum Ratings (Note 1)

Characteristics	aracteristics Symbol F		Unit
Supply voltage range	V _{CC}	-0.5 to 7.0	V
DC input voltage	V _{IN}	-0.5 to 7.0	V
DC output voltage	Vout	-0.5 to 7.0 (Note 2)	V
De output voltage	V001	-0.5 to V _{CC} + 0.5 (Note 3)	
Input diode current	lıк	-50	mA
Output diode current	lok	±50 (Note 4)	mA
DC output current	Ιουτ	±50	mA
Power dissipation	PD	180	mW
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA
Storage temperature	T _{stg}	-65 to 150	°C

Note1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 2: Output in off-state
- Note 3: High or low state. IOUT absolute maximum rating must be observed.
- Note 4: $V_{OUT} < GND, V_{OUT} > V_{CC}$

Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	1.8 to 5.5	V
Input voltage (DIR, OE)	V _{IN}	0 to 5.5	V
Output voltage	Maxim	0 to 5.5 (Note 2)	V
Output voltage	Vout	0 to V _{CC} (Note 3)	v
Operating temperature	T _{opr}	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 20(Vcc=3.3 ± 0.3V) 0 to 1(Vcc=5 ± 0.5V)	ms/V

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

Note 2: Output in off-state

Note 3: High or low state.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol		Test Condition		Ta = 25°C			Ta = −40 to 85°C		Unit	
Characteristics	Symbol			V _{CC} (V)	Min	Тур.	Max	Min	Max	Onic	
				1.8	—		1.65		1.65		
				2.3	—	—	1.85	—	1.85		
Positive threshold voltage	VP		—	3.0	—	—	2.20	—	2.20		
				4.5	—	—	3.15	—	3.15		
				5.5	—	—	3.85	—	3.85	v	
				1.8	0.15	—	—	0.15	—	v	
				2.3	0.45	—	—	0.45	—		
Negative threshold voltage	VN		_	3.0	0.90	—	—	0.90	—		
				4.5	1.35	—	—	1.35	—		
				5.5	1.65	—	—	1.65	_		
	V _H			1.8	0.15	_	1.05	0.15	1.05		
		_		2.3	0.20	_	1.10	0.20	1.10	v	
Hysteresis voltage				3.0	0.30	—	1.20	0.30	1.20		
				4.5	0.40	—	1.40	0.40	1.40		
				5.5	0.50	_	1.60	0.50	1.60		
		V _{IN} = V _{IH} or V _{IL}		1.8	1.7	1.8	_	1.7	_		
	V _{OH}		I _{OH} = -50 μA	3.0	2.9	3.0	_	2.9	_		
High-level output voltage				4.5	4.4	4.5	_	4.4	_		
			I _{OH} = -8 mA	3.0	2.58	_	_	2.48	_		
			I _{OH} = −16 mA	4.5	3.94	—	—	3.80	_		
				1.8	_	0.0	0.1	_	0.1	V	
		VIN	I _{OL} = 50 μA	3.0	_	0.0	0.1	_	0.1		
Low-level output voltage	VOL	= V _{IH} or		4.5	_	0.0	0.1	_	0.1		
		VIL	I _{OL} = 8 mA	3.0	_	_	0.36		0.44		
			I _{OL} = 16 mA	4.5	_	_	0.44	_	0.55		
3-state output off-state current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 5.5V		1.8 to 5.5	_	_	±0.5	_	±5.0	μΑ	
Power-off leakage current	IOFF	$V_{IN}/V_{OUT} = 5.5 V$		0	—	_	0.5	_	5.0	μA	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	_	±0.1	_	±1.0	μΑ	
Quiescent supply current	ICC	V _{IN} = V _C	c or GND	5.5	—	—	2.0	—	20.0	μA	

Timing Requirements (input: t_r = t_f = 3 ns)

Characteristics	Symbol	Test Condition	Ta = 25°C		Ta = −40 to 85°C	Unit	
			V _{CC} (V)	Тур.	Limit	Limit	
Minimum nulso width	t an		2.5 ± 0.2	—	7.0	7.0	
Minimum pulse width (CK)	t _{w (H)} t _{w (L)}	—	3.3 ± 0.3	—	5.0	5.0	ns
			5.0 ± 0.5		5.0	5.0	
	ts		2.5 ± 0.2		5.5	5.5	
Minimum set-up time		—	3.3 ± 0.3	—	3.5	3.5	ns
			5.0 ± 0.5	—	3.5	3.5	
	t _h		2.5 ± 0.2	_	2.0	2.0	
Minimum hold time		—	3.3 ± 0.3	—	1.5	1.5	ns
			5.0 ± 0.5	—	1.5	1.5	

AC Characteristics (input: t_r = t_f = 3 ns)

Characteristics	Symbol	Tes	est Condition		Ta = 25°C			Ta = −40 to 85°C		Unit
	- ,		V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	01110
			2.5 ± 0.2 -	15	_	9.1	16.6	1.0	20.0	-
				50		11.9	19.6	1.0	23.0	
Propagation delay time	t _{pLH}		22102	15		6.7	13.2	1.0	15.5	
(CK-Q)	t _{pHL}	_	3.3 ± 0.3	50		8.9	16.7	1.0	19.0	ns
· · ·			5.0 ± 0.5	15		5.0	8.6	1.0	10.0	
			5.0 ± 0.5	50		6.7	10.6	1.0	12.0	
			2.5 ± 0.2	15	-	7.6	16.1	1.0	19.0	
			2.5 ± 0.2	50	-	10.7	19.0	1.0	22.0	
3-state output enable	t _{pZL}	R _L = 1 kΩ	3.3 ± 0.3	15	_	5.7	12.8	1.0	15.0	ns
time	t _р zн	K ² = 1 K2	3.3 ± 0.3	50	-	8.1	16.3	1.0	18.5	115
			5.0 ± 0.5	15	_	4.2	9.0	1.0	10.5	
				50	_	6.1	11.0	1.0	12.5	
	t _{pLZ} t _{pHZ}	R _L = 1 kΩ	2.5 ± 0.2	50		13.6	17.5	1.0	20.0	ns
3-state output disable time			3.3 ± 0.3	50		10.5	15.0	1.0	17.0	
			5.0 ± 0.5	50		8.2	10.1	1.0	11.5	
			2.5 ± 0.2	15	60	95		50		
				50	50	75		40		
Maximum clock	f _{max}		3.3 ± 0.3	15	80	135		65		MHz
frequency	יmax			50	55	100		45		
			5.0 ± 0.5	15	130	180		110	_	-
			5.0 ± 0.5	50	85	135		75		
	tau		2.5 ± 0.2	50	—	—	2.0		2.0	
Output to output skew	t _{osLH}	(Note 1)	3.3 ± 0.3	50		—	1.5	_	1.5	ns
	t _{osHL}		5.0 ± 0.5	50	—	—	1.0	—	1.0	
Input capacitance	C _{IN}		_		—	4	10		10	pF
Output capacitance	C _{OUT}				_	6	_	_	_	pF
Power dissipation capacitance	C _{PD}			(Note 2)		26	_	_	_	pF

Note 1: Parameter guaranteed by design.

 $t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|$

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 (per F/F)$

And the total C_{PD} when n pcs. of latch operate can be gained by the following equation:

C_{PD} (total) = 14 + 12·n

Noise Characteristics (input: tr = tf = 3 ns)

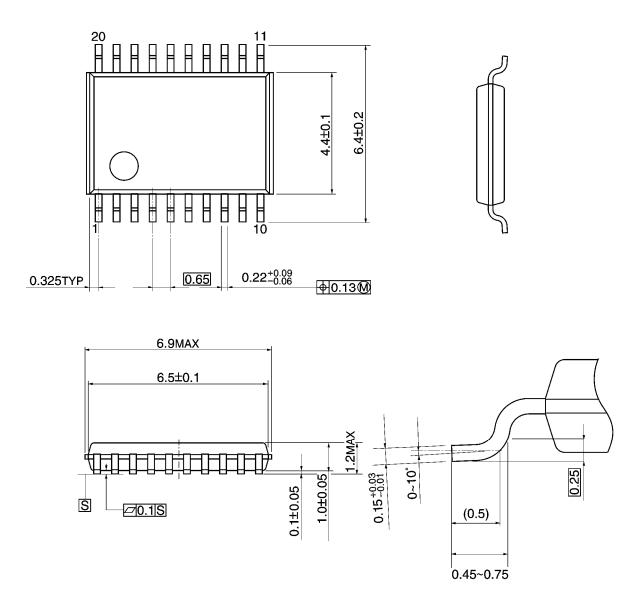
Characteristics	Symbol	Test Condition		Ta = 25°C		Unit
Characteristics	Symbol		V _{CC} (V)	Тур.	Max	Unit
Quiet output maximum dynamic V _{OI}	Vara	C _I = 50 pF	3.3	0.4	_	V
	VOLP	CL - 50 PF	5.0	0.8	-	v
Quiet output minimum dynamia Var	V _{OLV}	C _L = 50 pF	3.3	-0.1		v
Quiet output minimum dynamic V _{OL}			5.0	-0.4	_	
Minimum high level dynamic input voltage	V _{IHD}	C _L = 50 pF	5.0		3.5	V
Maximum low level dynamic input voltage	V _{ILD}	C _L = 50 pF	5.0	_	1.5	V

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Package Dimensions

TSSOP20-P-0044-0.65A

Unit: mm



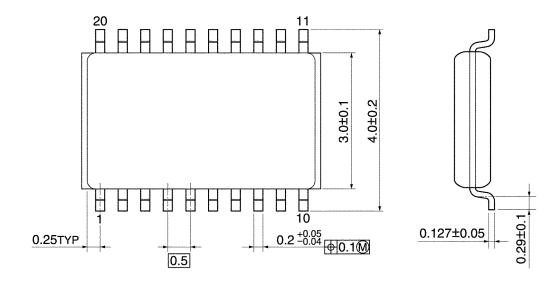
Weight: 0.08 g (typ.)

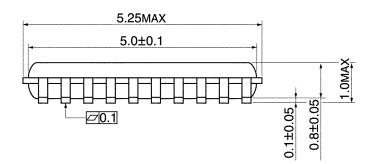


Package Dimensions

VSSOP20-P-0030-0.50

Unit: mm





Weight: 0.03 g (typ.)

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